NSN 5962-01-141-5687

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Body	Length:
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Between 1.180 inches and 1.220 inches

Body Width:

Between 0.585 inches and 0.615 inches

Body Height:

Between 0.060 inches and 0.105 inches

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-55.0/+125.0 degrees celsius

End Application:

4920-01-084-7157 e/i fscm 26916

Features Provided:

Hermetically sealed and monolithic and positive outputs and programmable and 3-state output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 15.0 volts power source

Time Rating Per Chacteristic:

500.00 nanoseconds propagation delay time, low to high level output and 500.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

28480-1818-0792 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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